

**3.5 GHz Delta-Sigma Modulated Fractional-N Frequency Synthesizer for Low Phase Noise Applications**

**Product Description**

Peregrine's PE97632 is a high performance fractional-N PLL capable of frequency synthesis up to 3.5 GHz. The device is designed for superior phase noise performance while providing an order of magnitude reduction in current consumption, when compared with the existing commercial space PLLs.

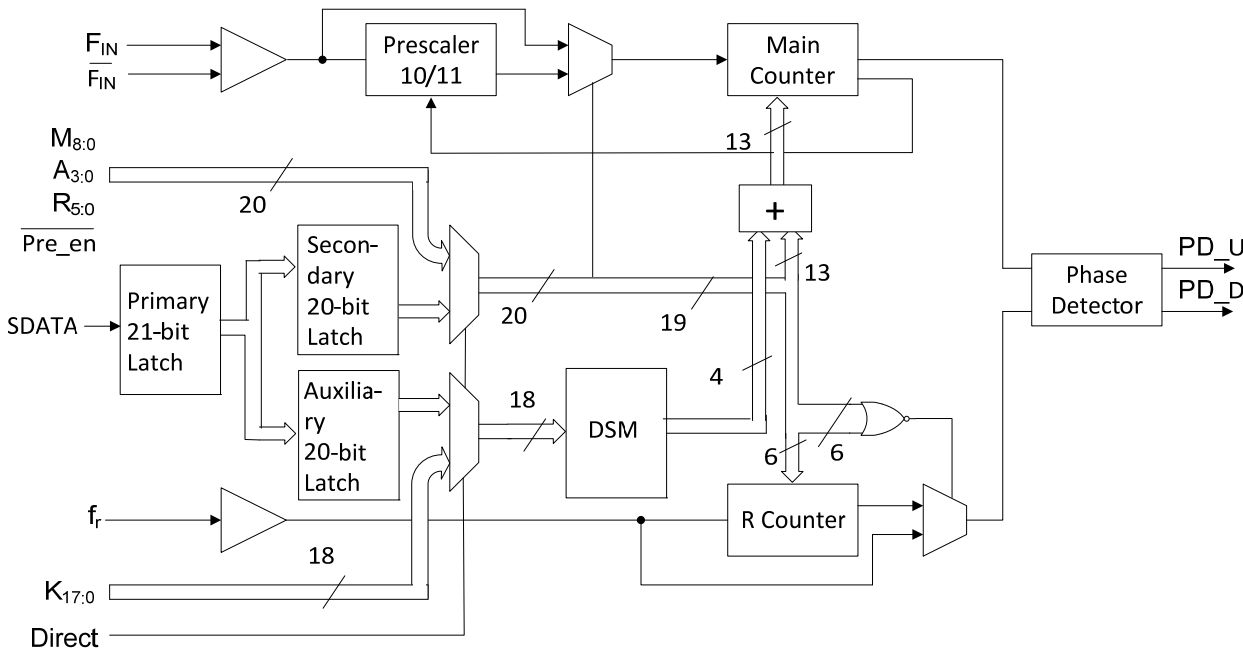
The PE97632 features a 10/11 dual modulus prescaler, counters, a delta sigma modulator and a phase comparator as shown in *Figure 1*. Counter values are programmable through either a serial interface or directly hard-wired.

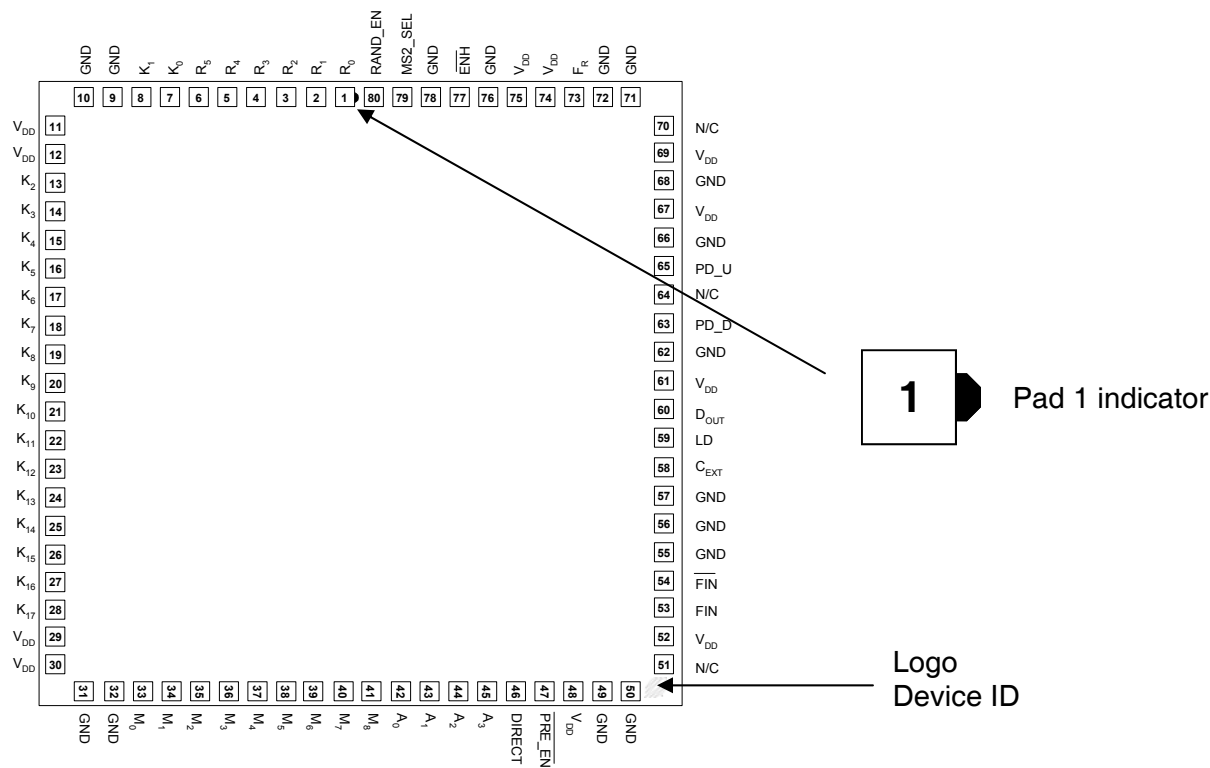
The PE97632 is optimized for commercial space applications. Single event latch-up (SEL) is physically impossible. Fabricated in Peregrine's patented UltraCMOS® technology, the PE97632 offers excellent RF performance and intrinsic radiation tolerance.

**Features**

- 3.5 GHz operation
- $\div 10/11$  dual modulus prescaler
- Phase detector output
- Serial or direct mode access
- Frequency selectivity: comparison frequency /  $2^{18}$
- Low power:  $-35$  mA @ 3.3V
- Radiation tolerant
- Ultra-low phase noise
- Pin compatible with the PE9763 (reference application note AN24 at [www.psemi.com](http://www.psemi.com))

**Figure 1. Block Diagram**



**Figure 2. Pin Configurations (Top View)**

**Table 1. Pin Descriptions**

Pad No.	Pad Name	Valid Mode	Type	Description
1	R <sub>0</sub>	Direct	Input	R counter bit0 (LSB).
2	R <sub>1</sub>	Direct	Input	R counter bit1.
3	R <sub>2</sub>	Direct	Input	R counter bit2.
4	R <sub>3</sub>	Direct	Input	R counter bit3.
5	R <sub>4</sub>	Direct	Input	R counter bit4.
6	R <sub>5</sub>	Direct	Input	R counter bit5 (MSB).
7	K <sub>0</sub>	Direct	Input	K counter bit0 (LSB).
8	K <sub>1</sub>	Direct	Input	K counter bit1.
9	GND		Downbond	Ground.
10	GND		Downbond	Ground.
11	V <sub>DD</sub>		Note 1	Digital core V <sub>DD</sub> .
12	V <sub>DD</sub>		Note 1	Digital core V <sub>DD</sub> .
13	K <sub>2</sub>	Direct	Input	K counter bit2.
14	K <sub>3</sub>	Direct	Input	K counter bit3.
15	K <sub>4</sub>	Direct	Input	K counter bit4.
16	K <sub>5</sub>	Direct	Input	K counter bit5.
17	K <sub>6</sub>	Direct	Input	K counter bit6.

**Table 1. Pad Descriptions (Cont.)**

Pad No.	Pad Name	Valid Mode	Type	Description
18	K <sub>7</sub>	Direct	Input	K counter bit7.
19	K <sub>8</sub>	Direct	Input	K counter bit8.
20	K <sub>9</sub>	Direct	Input	K counter bit9.
21	K <sub>10</sub>	Direct	Input	K counter bit10.
22	K <sub>11</sub>	Direct	Input	K counter bit11.
23	K <sub>12</sub>	Direct	Input	K counter bit12.
24	K <sub>13</sub>	Direct	Input	K counter bit13.
25	K <sub>14</sub>	Direct	Input	K counter bit14.
26	K <sub>15</sub>	Direct	Input	K counter bit15.
27	K <sub>16</sub>	Direct	Input	K counter bit16.
28	K <sub>17</sub>	Direct	Input	K counter bit17 (MSB).
29	V <sub>DD</sub>		Note 1	Digital core V <sub>DD</sub> .
30	V <sub>DD</sub>		Note 1	Digital core V <sub>DD</sub> .
31	GND		Downbond	Ground.
32	GND		Downbond	Ground.
33	M <sub>0</sub>	Direct	Input	M counter bit0 (LSB).
34	M <sub>1</sub>	Direct	Input	M counter bit1.
35	M <sub>2</sub>	Direct	Input	M counter bit2.
36	M <sub>3</sub>	Direct	Input	M counter bit3.
37	M <sub>4</sub>	Direct	Input	M counter bit4.
	S_WR	Serial	Input	Serial load enable input. While S_WR is "low", SDATA can be serially clocked. Primary register data are transferred to the secondary register on S_WR rising edge.
38	M <sub>5</sub>	Direct	Input	M counter bit5.
	SDATA	Serial	Input	Binary serial data input. Input data entered MSB first.
39	M <sub>6</sub>	Direct	Input	M counter bit6.
	SCLK	Serial	Input	Serial clock input. SDATA is clocked serially into the 21-bit primary register (E_WR "low") or the 8-bit enhancement register (E_WR "high") on the rising edge of SCLK.
40	M <sub>7</sub>	Direct	Input	M counter bit7.
41	M <sub>8</sub>	Direct	Input	M counter bit8 (MSB).
42	A <sub>0</sub>	Direct	Input	A counter bit0 (LSB).
43	A <sub>1</sub>	Direct	Input	A counter bit1.
	E_WR	Serial	Input	Enhancement register write enable. While E_WR is "high", SDATA can be serially clocked into the enhancement register on the rising edge of SCLK.
44	A <sub>2</sub>	Direct	Input	A counter bit2.
45	A <sub>3</sub>	Direct	Input	A counter bit3 (MSB).
46	DIRECT	Both	Input	Direct mode select. "High" enables direct mode. "Low" enables serial mode.
47	Pre_en	Direct	Input	Prescaler enable, active "low". When "high", F <sub>IN</sub> bypasses the prescaler.
48	V <sub>DD</sub>		Note 1	Digital core V <sub>DD</sub> .
49	GND		Downbond	Ground.
50	GND		Downbond	Ground.

**Table 1. Pad Descriptions (Cont.)**

Pad No.	Pad Name	Valid Mode	Type	Description
51	NC	Both		No connect.
52	V <sub>DD</sub>		Note 1	Prescaler V <sub>DD</sub> .
53	F <sub>IN</sub>	Both	Input	Prescaler input from the VCO. 3.5 GHz max frequency.
54	$\bar{F}_{IN}$	Both	Input	Prescaler complementary input. A bypass capacitor should be placed as close as possible to this pin and be connected in series with a 50Ω resistor directly to the ground plane.
55	GND		Downbond	Ground.
56	GND		Downbond	Ground.
57	GND		Downbond	Ground.
58	C <sub>EXT</sub>	Both	Output	Logical “NAND” of PD <sub>̄</sub> and PD <sub>̄</sub> terminated through an on chip, 2 kΩ series resistor. Connecting C <sub>EXT</sub> to an external capacitor will low pass filter the input to the inverting amplifier used for driving LD.
59	LD	Both	Output	Lock detect and open drain logical inversion of C <sub>EXT</sub> . When the loop is in lock, LD is high impedance, otherwise LD is a logic low (“0”).
60	D <sub>OUT</sub>	Both	Output	Data out function, enabled in enhancement mode.
61	V <sub>DD</sub>		Note 1	Output driver/V <sub>DD</sub> .
62	GND		Downbond	Ground.
63	PD <sub>̄</sub>	Both	Output	PD <sub>̄</sub> pulses down when f <sub>p</sub> leads f <sub>c</sub> .
64	NC	Both		No connect.
65	PD <sub>̄</sub>	Both	Output	PD <sub>̄</sub> pulses down when f <sub>c</sub> leads f <sub>p</sub> .
66	GND		Downbond	Ground.
67	V <sub>DD</sub>		Note 1	Output driver/V <sub>DD</sub> .
68	GND		Downbond	Ground.
69	V <sub>DD</sub>		Note 1	Phase detector V <sub>DD</sub> .
70	NC	Both		No connect.
71	GND		Downbond	Ground.
72	GND		Downbond	Ground.
73	f <sub>r</sub>	Both	Input	Reference frequency input.
74	V <sub>DD</sub>		Note 1	Reference V <sub>DD</sub> .
75	V <sub>DD</sub>		Note 1	Digital core V <sub>DD</sub> .
76	GND		Downbond	Ground.
77	ENH	Both	Input	Enhancement mode. When asserted low (“0”), enhancement register bits are functional.
78	GND		Downbond	Ground.
79	MS2_SEL	Both	Input	MASH 1-1 select. “High” selects MASH 1-1 mode. “Low” selects the MASH 1-1-1 mode.
80	RND_SEL	Both	Input	K register LSB toggle enable. “1” enables the toggling of LSB. This is equivalent to having an additional bit for the LSB of K register. The frequency offset as a result of enabling this bit is the phase detector comparison frequency / 2 <sup>19</sup> .

Notes: 1. All V<sub>DD</sub> pads are connected by diodes and must be supplied with the same positive voltage level.  
2. All digital input pads have 70 kΩ pull-down resistors to ground.

**Table 2. Absolute Maximum Ratings**

Symbol	Parameter/Condition	Min	Max	Unit
$V_{DD}$	Supply voltage	-0.3	4.0	V
$V_I$	Voltage on any input	-0.3	$V_{DD} + 0.3$	V
$I_I$	DC into any input	-10	+10	mA
$I_O$	DC into any output	-10	+10	mA
$T_{STG}$	Storage temperature range	-65	+150	°C

**Table 3. Operating Ratings**

Symbol	Parameter/Condition	Min	Max	Unit
$V_{DD}$	Supply voltage	2.85	3.45	V
$T_A$	Operating ambient temperature range	-40	+85	°C

**Table 4. ESD Ratings**

Symbol	Parameter/Condition	Level	Unit
$V_{ESD}$	ESD Voltage Human Body Model on all pins except pin 52 (Note 1)	1000	V
	ESD Voltage Human Body Model on pin 60 (Notes 1 and 2)	300	V

- Notes:
1. Periodically sampled, not 100% tested. Tested per MIL-STD-883, M3015 C2.
  2. Pin 60 is a test pin only. It is not used in normal operation.

### Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in *Table 4*.

### Latch-Up Immunity

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.

### ELDRS

UltraCMOS devices do not include bipolar minority carrier elements and; therefore, do not exhibit enhanced low-dose-rate sensitivity.

**Table 5. DC Characteristics @  $V_{DD} = 3.30V$ ,  $-40\text{ }^{\circ}C < TA < +85\text{ }^{\circ}C$ , unless otherwise specified**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$I_{DD}$	Operational supply current	Prescaler enabled, $V_{DD} = 2.85\text{--}3.45V$	20	35	45	mA
		Prescaler disabled, $V_{DD} = 2.85\text{--}3.45V$	8	15	23	mA
<b>All digital inputs: K[17:0], R[5:0], M[8:0], A[3:0], Direct, <math>\overline{Pre\_en}</math>, <math>\overline{Rand\_en}</math>, M2_sel, <math>\overline{ENH}</math> (contains a 70 k<math>\Omega</math> pull-down resistor)</b>						
$V_{IH}$	High level input voltage	$V_{DD} = 2.85\text{--}3.45V$	$0.7 \times V_{DD}$			V
$V_{IL}$	Low level input voltage	$V_{DD} = 2.85\text{--}3.45V$			$0.3 \times V_{DD}$	V
$I_{IH}$	High level input current	$V_{IH} = V_{DD} = 3.45V$			100	$\mu A$
$I_{IL}$	Low level input current	$V_{IL} = 0, V_{DD} = 3.45V$	-1			$\mu A$
<b>Reference divider input: <math>f_r</math></b>						
$I_{IHR}$	High level input current	$V_{IH} = V_{DD} = 3.45V$			100	$\mu A$
$I_{ILR}$	Low level input current	$V_{IL} = 0, V_{DD} = 3.45V$	-100			$\mu A$
<b>Counter and phase detector outputs: <math>\overline{PD\_D}</math>, <math>\overline{PD\_U}</math></b>						
$V_{OLD}$	Output voltage LOW	$I_{OUT} = 6\text{ mA}$			0.4	V
$V_{OHD}$	Output voltage HIGH	$I_{OUT} = -3\text{ mA}$	$V_{DD}-0.4$			V
<b>Digital test outputs: <math>D_{OUT}</math></b>						
$V_{OLD}$	Output voltage LOW	$I_{OUT} = 200\text{ }\mu A$			0.4	V
$V_{OHD}$	Output voltage HIGH	$I_{OUT} = -200\text{ }\mu A$	$V_{DD}-0.4$			V
<b>Lock detect outputs: (<math>C_{EXT}</math>, LD)</b>						
$V_{OLC}$	Output voltage LOW, $C_{EXT}$	$I_{OUT} = 0.1\text{ mA}$			0.4	V
$V_{OHC}$	Output voltage HIGH, $C_{EXT}$	$I_{OUT} = -0.1\text{ mA}$	$V_{DD}-0.4$			V
$V_{OLLD}$	Output voltage LOW, LD	$I_{OUT} = 1\text{ mA}$			0.4	V

**Table 6. AC Characteristics @  $V_{DD} = 3.30V$ ,  $-40\text{ }^{\circ}C < TA < +85\text{ }^{\circ}C$ , unless otherwise specified<sup>5</sup>**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Control interface and latches (see Figures 3 and 4)</b>						
$f_{Clk}$	Serial data clock frequency <sup>1</sup>				10	MHz
$t_{ClkH}$	Serial clock HIGH time		30			ns
$t_{ClkL}$	Serial clock LOW time		30			ns
$t_{DSU}$	SDATA set-up time to SCLK rising edge		10			ns
$t_{DHLD}$	SDATA hold time after SCLK rising edge		10			ns
$t_{PW}$	S_WR pulse width		30			ns
$t_{CWR}$	SCLK rising edge to S_WR rising edge		30			ns
$t_{CE}$	SCLK falling edge to E_WR transition		30			ns
$t_{WRC}$	S_WR falling edge to SCLK rising edge		30			ns
$t_{EC}$	E_WR transition to SCLK rising edge		30			ns
<b>Main divider (including prescaler)<sup>4</sup></b>						
$P_{Fin}$	Input level range	External AC coupling 275 MHz $\leq$ Freq $\leq$ 3200 MHz	-5		5	dBm
		External AC coupling 3.2 GHz < Freq $\leq$ 3.5 GHz 3.15V $\leq$ VDD $\leq$ 3.45V	0		5	dBm
<b>Main divider (prescaler bypassed)<sup>4</sup></b>						
$F_{IN}$	Operating frequency		50		300	MHz
$P_{F\_IN}$	Input level range	External AC coupling	-5		5	dBm
<b>Reference divider</b>						
$f_r$	Operating frequency <sup>3</sup>				100	MHz
$P_{FR}$	Reference input power <sup>2</sup>	Single ended input	-2		10	dBm
<b>Phase detector</b>						
$f_c$	Comparison frequency <sup>3</sup>				50	MHz
<b>SSB phase noise (<math>F_{IN} = 1.9\text{ GHz}</math>, <math>f_r = 20\text{ MHz}</math>, <math>f_c = 20\text{ MHz}</math>, <math>LBW = 50\text{ kHz}</math>, <math>V_{DD} = 3.3V</math>, <math>Temp = +25\text{ }^{\circ}C</math>)<sup>4</sup></b>						
$\Phi_N$	Phase noise	100 Hz offset		-89	-83	dBc/Hz
$\Phi_N$	Phase noise	1 kHz offset		-96	-91	dBc/Hz
$\Phi_N$	Phase noise	10 kHz offset		-101	-96	dBc/Hz
<b>SSB phase noise (<math>F_{IN} = 1.9\text{ GHz}</math>, <math>f_r = 20\text{ MHz}</math>, <math>f_c = 20\text{ MHz}</math>, <math>LBW = 50\text{ kHz}</math>, <math>V_{DD} = 3.0V</math>, <math>Temp = +25\text{ }^{\circ}C</math>)<sup>4</sup></b>						
$\Phi_N$	Phase noise	100 Hz offset		-84	-70	dBc/Hz
$\Phi_N$	Phase noise	1 kHz offset		-92	-81	dBc/Hz
$\Phi_N$	Phase noise	10 kHz offset		-100	-89	dBc/Hz

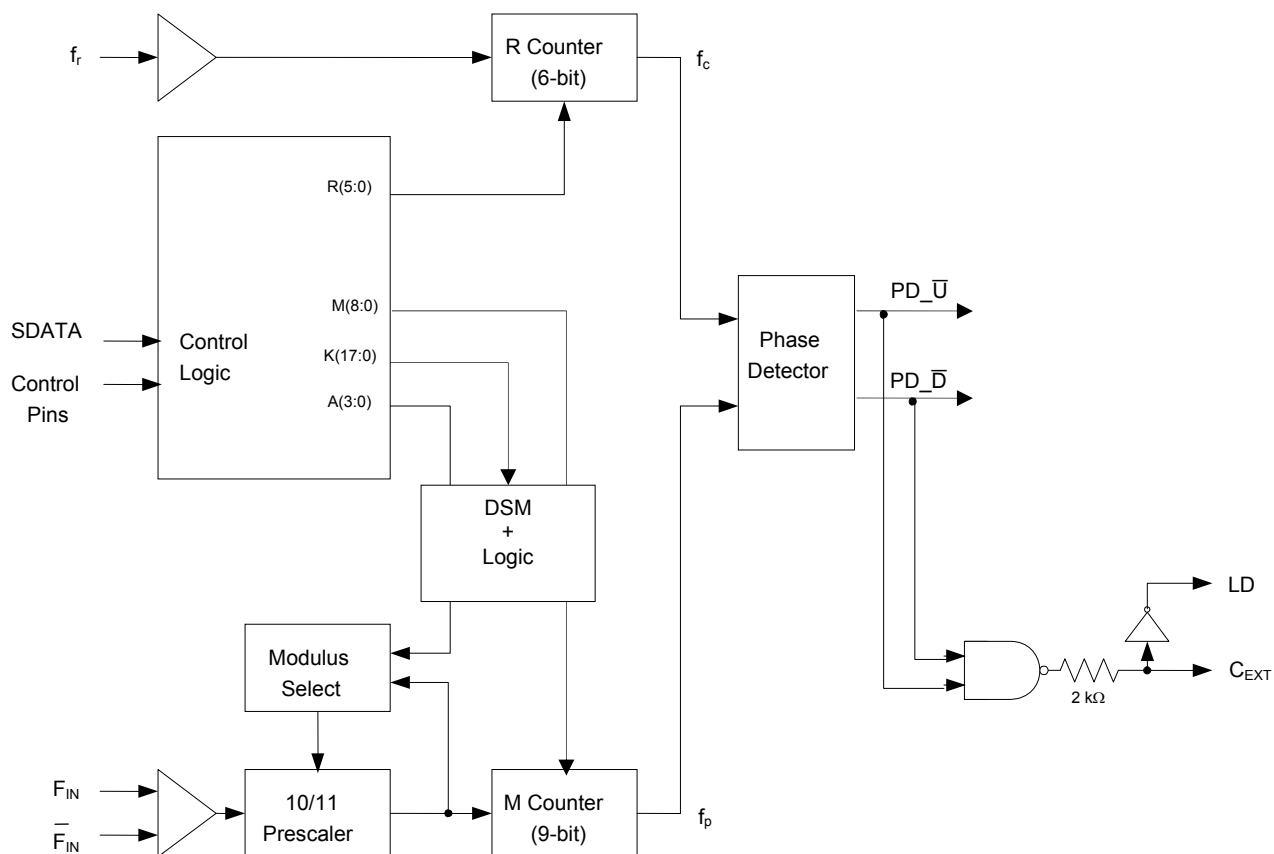
- Notes:
- $f_{Clk}$  is verified during the functional pattern test. Serial programming sections of the functional pattern are clocked at 10 MHz to verify  $f_{Clk}$  specification.
  - CMOS logic levels can be used to drive reference input if DC coupled. Voltage input needs to be a minimum of 0.5  $V_{PP}$ . For optimum phase noise performance, the reference input falling edge rate should be faster than 80 mV/ns.
  - Parameter is guaranteed through characterization only and is not tested.
  - Parameter is verified during the element evaluation and are not tested for die sales.
  - All information in Table 6 is not tested at wafer sort.

### Functional Description

The PE97632 consists of a prescaler, counters, an 18-bit delta-sigma modulator (DSM) and a phase detector. The dual modulus prescaler divides the VCO frequency by either 10/11, depending on the value of the modulus select. Counters “R” and “M” divide the reference and prescaler output, respectively, by integer values stored in a 20-bit register. An additional counter (“A”) is used in the modulus select logic. The DSM modulates the “A” counter outputs in order to achieve the desired fractional step.

The phase-frequency detector generates up and down frequency control signals. Data is written into the internal registers via the three wire serial bus. There are also various operational and test modes and a lock detect output.

**Figure 3. Functional Block Diagram**





## Main Counter Chain

### Normal Operating Mode

Setting the  $\overline{\text{Pre\_en}}$  control bit “low” enables the  $\div 10/11$  prescaler. The main counter chain then divides the RF input frequency ( $F_{\text{IN}}$ ) by an integer or fractional number derived from the values in the “M” and “A” counters and the DSM input word K. The accumulator size is 18 bit, so the fractional value is fixed from the ratio  $K/2^{18}$ . There is an additional bit in the DSM that acts like an extra bit (19<sup>th</sup> bit). This bit is enabled by asserting the pin  $\text{RAND\_SEL}$  to “high”. Enabling this bit has the benefit of reducing the spurious levels. However, a small frequency offset will occur. This positive frequency offset is calculated with the following equation.

$$f_{\text{offset}} = [F_R / (R+1)] / 2^{19} \quad (1)$$

All of the following equations do not take into account this frequency offset. If this offset is important to a specific frequency plan, appropriate account needs to be taken.

In the normal mode, the output from the main counter chain ( $f_p$ ) is related to the VCO frequency ( $F_{\text{IN}}$ ) by the following equation:

$$f_p = F_{\text{IN}} / [10 \times (M+1) + A + K/2^{18}] \quad (2)$$

where  $A \leq M + 1$ ,  $1 \leq M \leq 511$

When the loop is locked,  $F_{\text{IN}}$  is related to the reference frequency ( $F_R$ ) by the following equation:

$$F_{\text{IN}} = [10 \times (M+1) + A + K/2^{18}] \times [F_R / (R+1)] \quad (3)$$

where  $A \leq M + 1$ ,  $1 \leq M \leq 511$

A consequence of the upper limit on A is that  $F_{\text{IN}}$  must be greater than or equal to  $90 \times [F_R / (R+1)]$  to obtain contiguous channels. The A counter can accept values as high as 15, but in typical operation it will cycle from 0 to 9 between increments in M.

Programming the M counter with the minimum allowed value of “1” will result in a minimum M counter divide ratio of “2”.

### Prescaler Bypass Mode (\*)

Setting the frequency control register bit  $\text{Pre\_en}$  “high” allows  $F_{\text{IN}}$  to bypass the  $\div 10/11$  prescaler. In this mode, the prescaler and A counter are powered down, and the input VCO frequency is divided by the M counter directly. The following equation relates  $F_{\text{IN}}$  to the reference frequency  $F_R$ :

$$F_{\text{IN}} = (M+1) \times [F_R / (R+1)] \quad (4)$$

where  $1 \leq M \leq 511$

(\*) Only integer mode

In frequency bypass mode, neither A counter or K counter is used. Therefore, only integer-N operation is possible.

## Reference Counter

The reference counter chain divides the reference frequency,  $F_R$ , down to the phase detector comparison frequency,  $f_c$ .

The output frequency of the 6-bit R counter is related to the reference frequency by the following equation:

$$f_c = F_R / (R+1) \quad (5)$$

where  $0 \leq R \leq 63$

Note that programming R with “0” will pass the reference frequency,  $F_R$ , directly to the phase detector.

## Register Programming

### Serial Interface Mode

While the  $\text{E\_WR}$  input is “low” and the  $\text{S\_WR}$  input is “low”, serial input data (SDATA input),  $B_0$  to  $B_{20}$ , are clocked serially into the primary register on the rising edge of SCLK, MSB ( $B_0$ ) first. The LSB is used as address bit. When “0”, the contents from the primary register are transferred into the secondary register on the rising edge of either  $\text{S\_WR}$  according to the timing diagrams shown in *Figure 4*. When “1”, data is transferred to the auxiliary register according to the same timing diagram. The secondary register is used to program the various counters, while the auxiliary register is used to program the DSM.

Data are transferred to the counters as shown in *Table 8*.

While the E\_WR input is “high” and the S\_WR input is “low”, serial input data (SDATA input), B<sub>0</sub> to B<sub>7</sub>, are clocked serially into the enhancement register on the rising edge of SCLK, MSB (B<sub>0</sub>) first. The enhancement register is double buffered to prevent inadvertent control changes during serial loading, with buffer capture of the serially entered data performed on the falling edge of E\_WR according to the timing diagram shown in *Figure 4*. After the falling edge of E\_WR, the data provide control bits as shown in *Table 9* will have their bit functionality enabled by asserting the ENH input “low”.

### Direct Interface Mode

Direct Interface Mode is selected by setting the “Direct” input “high”.

Counter control bits are set directly at the pins as shown in *Table 7* and *Table 8*.

**Table 7. Secondary Register Programming**

Interface Mode	ENH	R <sub>5</sub>	R <sub>4</sub>	M <sub>8</sub>	M <sub>7</sub>	Pre_en	M <sub>6</sub>	M <sub>5</sub>	M <sub>4</sub>	M <sub>3</sub>	M <sub>2</sub>	M <sub>1</sub>	M <sub>0</sub>	R <sub>3</sub>	R <sub>2</sub>	R <sub>1</sub>	R <sub>0</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	ADDR
Direct	1	R <sub>5</sub>	R <sub>4</sub>	M <sub>8</sub>	M <sub>7</sub>	Pre_en	M <sub>6</sub>	M <sub>5</sub>	M <sub>4</sub>	M <sub>3</sub>	M <sub>2</sub>	M <sub>1</sub>	M <sub>0</sub>	R <sub>3</sub>	R <sub>2</sub>	R <sub>1</sub>	R <sub>0</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	X
Serial*	1	B <sub>0</sub>	B <sub>1</sub>	B <sub>2</sub>	B <sub>3</sub>	B <sub>4</sub>	B <sub>5</sub>	B <sub>6</sub>	B <sub>7</sub>	B <sub>8</sub>	B <sub>9</sub>	B <sub>10</sub>	B <sub>11</sub>	B <sub>12</sub>	B <sub>13</sub>	B <sub>14</sub>	B <sub>15</sub>	B <sub>16</sub>	B <sub>17</sub>	B <sub>18</sub>	B <sub>19</sub>	0

Note: \* Serial data clocked serially on SCLK rising edge while E\_WR “low” and captured in secondary register on S\_WR rising edge.

↑  
MSB (first in)

↑  
(last in) LSB

**Table 8. Auxiliary Register Programming**

Interface Mode	ENH	K <sub>17</sub>	K <sub>16</sub>	K <sub>15</sub>	K <sub>14</sub>	K <sub>13</sub>	K <sub>12</sub>	K <sub>11</sub>	K <sub>10</sub>	K <sub>9</sub>	K <sub>8</sub>	K <sub>7</sub>	K <sub>6</sub>	K <sub>5</sub>	K <sub>4</sub>	K <sub>3</sub>	K <sub>2</sub>	K <sub>1</sub>	K <sub>0</sub>	Rsrv	Rsrv	ADDR
Direct	1	K <sub>17</sub>	K <sub>16</sub>	K <sub>15</sub>	K <sub>14</sub>	K <sub>13</sub>	K <sub>12</sub>	K <sub>11</sub>	K <sub>10</sub>	K <sub>9</sub>	K <sub>8</sub>	K <sub>7</sub>	K <sub>6</sub>	K <sub>5</sub>	K <sub>4</sub>	K <sub>3</sub>	K <sub>2</sub>	K <sub>1</sub>	K <sub>0</sub>	X	X	X
Serial*	1	B <sub>0</sub>	B <sub>1</sub>	B <sub>2</sub>	B <sub>3</sub>	B <sub>4</sub>	B <sub>5</sub>	B <sub>6</sub>	B <sub>7</sub>	B <sub>8</sub>	B <sub>9</sub>	B <sub>10</sub>	B <sub>11</sub>	B <sub>12</sub>	B <sub>13</sub>	B <sub>14</sub>	B <sub>15</sub>	B <sub>16</sub>	B <sub>17</sub>	B <sub>18</sub>	B <sub>19</sub>	1

Note: \* Serial data clocked serially on SCLK rising edge while E\_WR “low” and captured in secondary register on S\_WR rising edge.

↑  
MSB (first in)

↑  
(last in) LSB

**Table 9. Enhancement Register Programming**

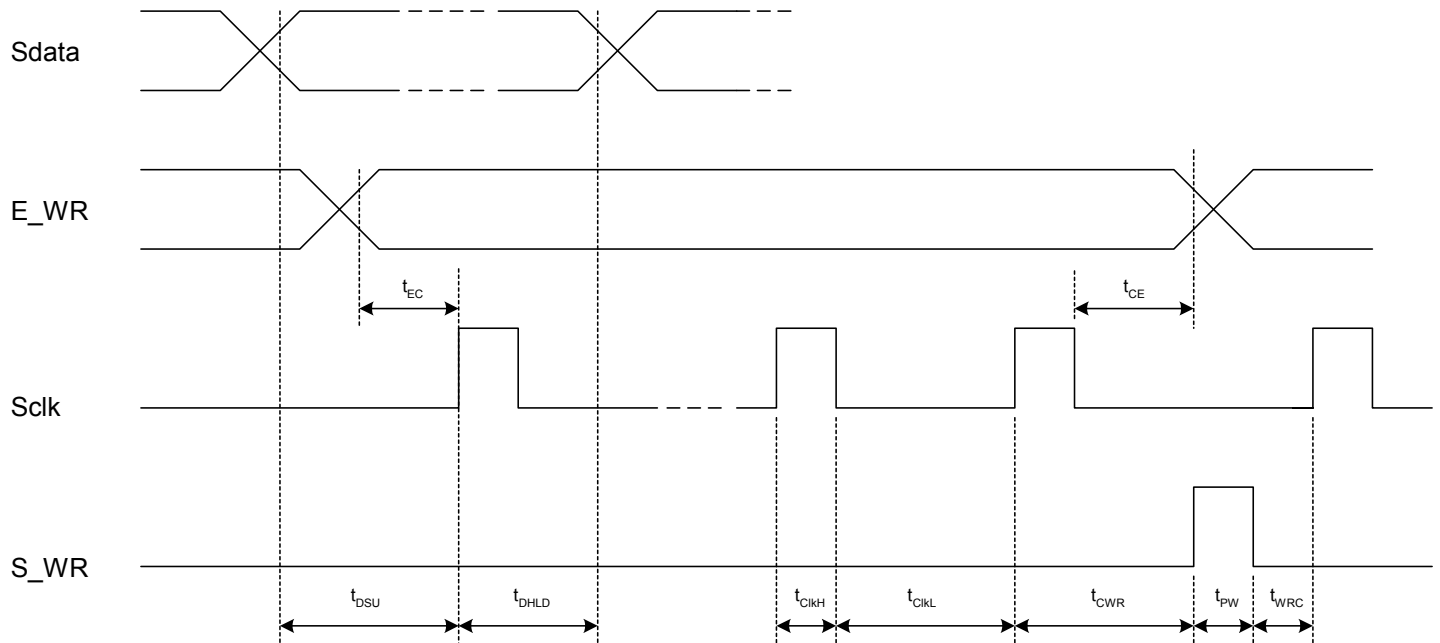
Interface Mode	ENH	Reserved	Reserved	f <sub>p</sub> Output	Power Down	Counter Load	MSEL Output	f <sub>c</sub> Output	LD Disable
Serial*	0	B <sub>0</sub>	B <sub>1</sub>	B <sub>2</sub>	B <sub>3</sub>	B <sub>4</sub>	B <sub>5</sub>	B <sub>6</sub>	B <sub>7</sub>

Note: \* Serial data clocked serially on SCLK rising edge while E\_WR “high” and captured in the double buffer on E\_WR falling edge.

↑  
MSB (first in)

↑  
(last in) LSB

**Figure 4. Serial Interface Mode Timing Diagram**



## Enhancement Register

The functions of the enhancement register bits are shown below with all bits active “high”.

**Table 10. Enhancement Register Bit Functionality**

Bit	Bit Function	Description
Bit 0	Reserve*	Reserved.
Bit 1	Reserve*	Reserved.
Bit 2	$f_p$ output	Drives the M counter output onto the D <sub>OUT</sub> output.
Bit 3	Power down	Power down of all functions except programming interface.
Bit 4	Counter load	Immediate and continuous load of counter programming.
Bit 5	MSEL output	Drives the internal dual modulus prescaler modulus select (MSEL) onto the D <sub>OUT</sub> output.
Bit 6	$f_c$ output	Drives the reference counter output onto the D <sub>OUT</sub> output.
Bit 7	LD disable	Disables the LD pin for quieter operation.

Note: \* Program to 0.

### Phase Detector

The phase detector is triggered by rising edges from the main counter ( $f_p$ ) and the reference counter ( $f_c$ ). It has two outputs, namely  $PD_{\bar{U}}$  and  $PD_{\bar{D}}$ . If the divided VCO leads the divided reference in phase or frequency ( $f_p$  leads  $f_c$ ),  $PD_{\bar{D}}$  pulses “low”. If the divided reference leads the divided VCO in phase or frequency ( $f_c$  leads  $f_p$ ),  $PD_{\bar{U}}$  pulses “low”. The width of either pulse is directly proportional to phase offset between the two input signals,  $f_p$  and  $f_c$ .

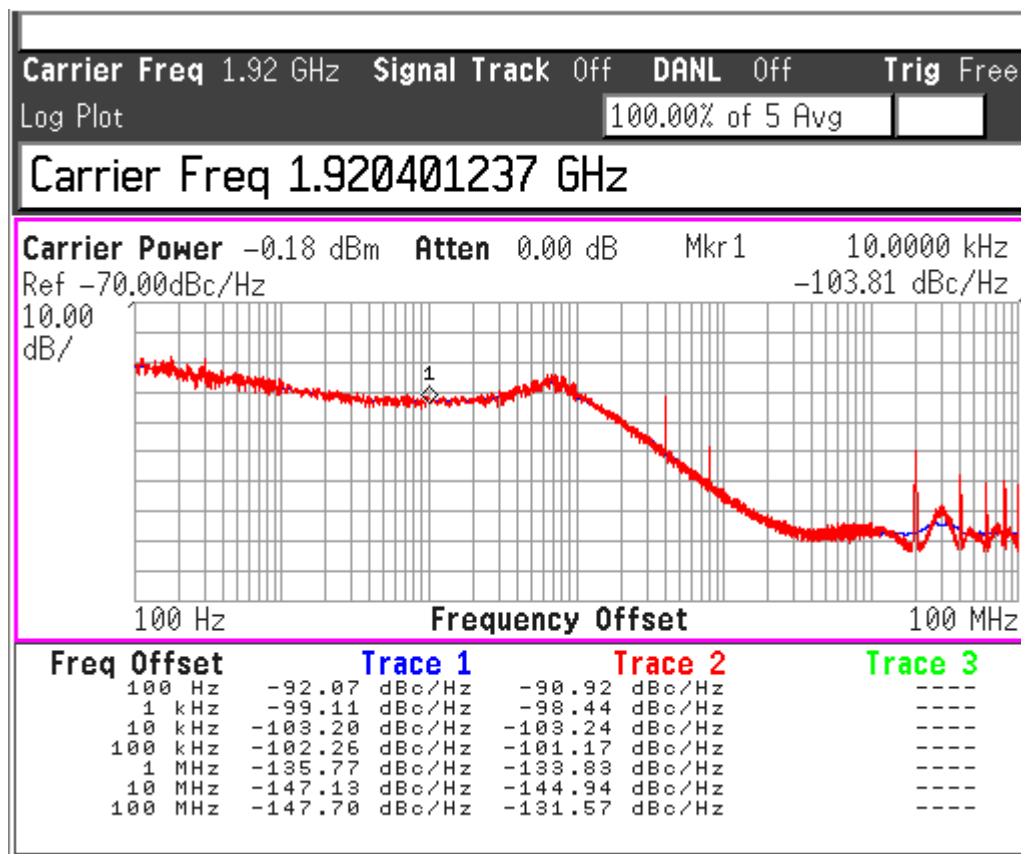
For the UP and DOWN mode,  $PD_{\bar{U}}$  and  $PD_{\bar{D}}$  drive an active loop filter which controls the VCO tune voltage. The phase detector gain is equal to  $V_{DD} / 2\pi$ .

$PD_{\bar{U}}$  pulses cause an increase in VCO frequency and  $PD_{\bar{D}}$  pulses cause a decrease in VCO frequency, for a positive kV VCO.

A lock detect output, LD is also provided, via the pin  $C_{EXT}$ .  $C_{EXT}$  is the logical “NAND” of  $PD_{\bar{U}}$  and  $PD_{\bar{D}}$  waveforms, which is driven through a series 2 k $\Omega$  resistor. Connecting  $C_{EXT}$  to an external shunt capacitor provides low pass filtering of this signal.  $C_{EXT}$  also drives the input of an internal inverting comparator with an open drain output. Thus LD is an “AND” function of  $PD_{\bar{U}}$  and  $PD_{\bar{D}}$ .

Figure 5. Typical Phase Noise

A typical phase noise plot is shown below. “Trace 1” is the smoothed average and “Trace 2” is the raw data.



Test conditions: MASH 1-1 mode,  $F_{OUT} = 1.9204$  GHz,  $F_{COMPARISON} = 20$  MHz,  $V_{DD} = 3.3V$ , temp = +25 °C, loop bandwidth = 50 kHz.

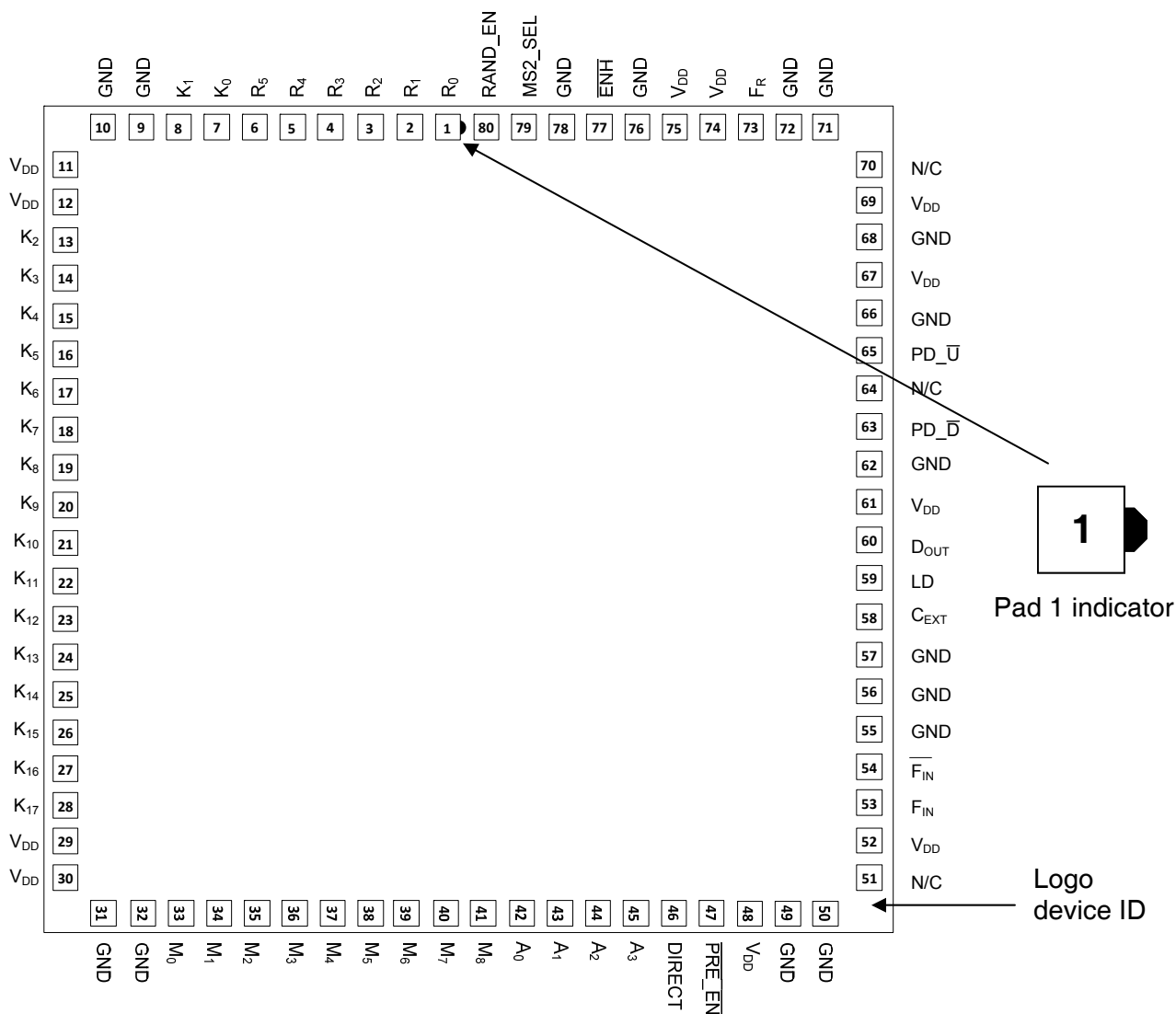


Table 11. Mechanical Specifications

Parameter	Min	Typ	Max	Unit	Test Condition
Die size, drawn (x,y)		3306 × 3306		µm	As drawn
Die size, singulated (x,y)*	3522 × 3470 3652 × 3470	3622 × 3570 3752 × 3570	3722 × 3670 3852 × 3670	µm	Including excess sapphire, max. tolerance = ±100 µm
Wafer thickness	180	200	220	µm	
Wafer size		150		mm	

Note: \* There are two different singulated die sizes per reticle.

Figure 7. Pad Numbering<sup>1,2</sup>



- Notes: 1. All pad locations originate from the die center and refer to the center of the pad.
- 2. Minimum pad pitch is 150 µm. Pad openings are 90 µm.

Table 12. Pin Coordinates

Pin #	Pin Name	Pin Center (μm)	
		X	Y
1	R0	-75.0	1578.8
2	R1	-225.0	1578.8
3	R2	-375.0	1578.8
4	R3	-525.0	1578.8
5	R4	-675.0	1578.8
6	R5	-825.0	1578.8
7	K0	-975.0	1578.8
8	K1	-1125.0	1578.8
9	GND	-1275.0	1578.8
10	GND	-1425.0	1578.8
11	V <sub>DD</sub>	-1578.8	1425.0
12	V <sub>DD</sub>	-1578.8	1275.0
13	K2	-1578.8	1125.0
14	K3	-1578.8	975.0
15	K4	-1578.8	825.0
16	K5	-1578.8	675.0
17	K6	-1578.8	525.0
18	K7	-1578.8	375.0
19	K8	-1578.8	225.0
20	K9	-1578.8	75.0
21	K10	-1578.8	-75.0
22	K11	-1578.8	-225.0
23	K12	-1578.8	-375.0
24	K13	-1578.8	-525.0
25	K14	-1578.8	-675.0
26	K15	-1578.8	-825.0
27	K16	-1578.8	-975.0
28	K17	-1578.8	-1125.0
29	V <sub>DD</sub>	-1578.8	-1275.0
30	V <sub>DD</sub>	-1578.8	-1425.0
31	GND	-1425.0	-1578.8
32	GND	-1275.0	-1578.8
33	M0	-1125.0	-1578.8
34	M1	-975.0	-1578.8
35	M2	-825.0	-1578.8
36	M3	-675.0	-1578.8
37	M4	-525.0	-1578.8
38	M5	-375.0	-1578.8
39	M6	-225.0	-1578.8
40	M7	-75.0	-1578.8

Pin #	Pin Name	Pin Center (μm)	
		X	Y
41	M8	75.0	-1578.8
42	A0	225.0	-1578.8
43	A1	375.0	-1578.8
44	A2	525.0	-1578.8
45	A3	675.0	-1578.8
46	DIRECT	825.0	-1578.8
47	$\overline{\text{PRE\_EN}}$	975.0	-1578.8
48	V <sub>DD</sub>	1125.0	-1578.8
49	GND	1275.0	-1578.8
50	GND	1425.0	-1578.8
51	V <sub>DD</sub>	1578.8	-1425.0
52	V <sub>DD</sub>	1578.8	-1275.0
53	F <sub>IN</sub>	1578.8	-1125.0
54	F <sub>IN</sub>	1578.8	-975.0
55	GND	1578.8	-825.0
56	GND	1578.8	-675.0
57	GND	1578.8	-525.0
58	C <sub>EXT</sub>	1578.8	-375.0
59	LD	1578.8	-225.0
60	DO	1578.8	-75.0
61	V <sub>DD</sub>	1578.8	75.0
62	GND	1578.8	225.0
63	PD <sub>̄</sub>	1578.8	375.0
64	NC	1578.8	525.0
65	PD <sub>̄</sub>	1578.8	675.0
66	GND	1578.8	825.0
67	V <sub>DD</sub>	1578.8	975.0
68	GND	1578.8	1125.0
69	V <sub>DD</sub>	1578.8	1275.0
70	V <sub>DD</sub>	1578.8	1425.0
71	GND	1425.0	1578.8
72	GND	1275.0	1578.8
73	F <sub>R</sub>	1125.0	1578.8
74	V <sub>DD</sub>	975.0	1578.8
75	V <sub>DD</sub>	825.0	1578.8
76	GND	675.0	1578.8
77	$\overline{\text{ENH}}$	525.0	1578.8
78	GND	375.0	1578.8
79	MASH2SEL	225.0	1578.8
80	RAND_EN	75.0	1578.8

**Table 13. Ordering Information**

Order Code	Part Marking	Description	Specification	Package	Shipping Method
97632-98*	FA97632	Engineering die		Waffle pack	Waffle pack (5 units max)
97632-99	FA97632	Flight die	81-0015	Waffle pack	100 units / waffle pack
97632-00	PE97632 EK	Evaluation kit			1 / Box

Note: \* The 97632-98 die are ES (engineering sample) units intended as initial evaluation devices for customers of the 97632-99 flight die. The 97632-98 ES die provide the same electrical functionality and performance as the 97632-99 flight die, but is processed to a non-compliant flow (e.g. no QCI coverage or element evaluation data). These die are obtained from non-qualified wafers so are not suitable for qualification, production, radiation testing or flight use.

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